

L Numb r	Hits	S earch T xt	DB	Time stamp
1	82	((high near density) near10 ((read near only) or rom) and (heavily near doped))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 14:53
2	78	((high near density) near10 ((read near only) or rom) and (heavily near doped)) and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 14:54
3	2	((high near density) near10 ((read near only) or rom) and (heavily near doped)).clm. and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 14:54
4	77	((read near only) or rom) and (heavily near doped)).clm. and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 14:55
5	59	((read near only) or rom) and (heavily near doped)).clm. and substrate.clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 14:55
6	24	((read near only) or rom) and (heavily near doped)).clm. and substrate.clm. and ((conductive or conductivity) near type).clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 14:57
7	20	((read near only) or rom) and (heavily near doped)).clm. and substrate.clm. and ((conductive or conductivity) near type).clm. and gate.clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 14:57
8	6	((read near only) or rom) and (heavily near doped)).clm. and substrate.clm. and ((conductive or conductivity) near type).clm. and gate.clm. and (high near density)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 14:59
9	1161	(heavily near doped near region).clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 14:59
10	30	(heavily near doped near region). Im. and (rom r (read near only)).clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 15:02

11	26	(h avily n ar d p d n arr gi n).clm. and (rom r (read near nly)). clm. and gat .clm.	USPAT; US-PGPUB; EP ; JP ; DERWENT; IBM_TDB USPAT; US-PGPUB;	2004/06/21 15:03
12	1	(h avily near dop d near r gion).clm. near10 (rom or (read near only)).clm. near10 gate.clm.	EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB;	2004/06/21 15:02
13	14	((heavily near doped near region).clm. near10 gate.clm.) and (rom or (read near only)).clm.)	EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB;	2004/06/21 15:07
14	6	((heavily near doped near region).clm. near10 gate.clm.) and (rom or (read near only)).clm.) and (high near density)	EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB;	2004/06/21 15:04
15	481	(substrate same ((first or second) near5 doped near region) same heavily).clm.	EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB;	2004/06/21 15:08
16	255	(substrate same ((first or second) near5 doped near region) same (heavily near doped near region)).clm.	EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB;	2004/06/21 15:08
17	158	(substrate same ((first or second) near2 doped near region) same (heavily near doped near region)).clm.	EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB;	2004/06/21 15:08
18	0	(substrate same ((first or second) near2 doped near region) same (heavily near doped near region) same (rom or (read near only))).clm.	EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB;	2004/06/21 15:09
19	13	(substrate same ((first or second) near2 doped near region) same (heavily near doped near region)).clm. and (rom or (read near only))	EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB;	2004/06/21 15:10
20	7	(substrate same ((first or second) near2 doped near region) same (heavily near d p d near regi n)).clm. and (r m r (read near only)) and (high near density)	EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB;	2004/06/21 15:11

21	6	(substrate same ((first or sec nd) near2 d ped near r gi n) same (h avily near d p d near regi n)).clm. and (r m or (r ad n ar nly)) and (high near d nsity) and ((conductivity or c nductive) n ar typ).clm.	USPAT; US-P PUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 15:11
22	1	(substrate same ((first or second) near2 doped near region) same (heavily near doped near region)).clm. and (rom or (read near only)) and (high near density).ti,ab,clm. and ((conductivity or conductive) near type).clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 15:13
23	6	(high near density near (rom or (read near only))).ti,ab,clm. and ((conductive or conductivity) near type).clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 15:14
24	2	(high near density near (rom or (read near only))).ti,ab,clm. and ((conductive or conductivity) near type).clm. and (heavily near doped).clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 15:15
25	0	(high near density near (rom or (read near only))).ti,ab,clm. and ((conductive or conductivity) near type).clm. and (heavily near doped).clm. and well.clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 15:16
26	0	(high near density near (rom or (read near only))) and ((conductive or conductivity) near type).clm. and (heavily near doped).clm. and well.clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 15:16
27	15	(rom or (read near only)) and ((conductive or conductivity) near type).clm. and (heavily near doped).clm. and well.clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 15:19
28	99	(rom or (read near only)) and ((conductive or conductivity) near type).clm. and (heavily near doped).clm. and gate.clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 15:19
29	91	(rom or (read near only)) and (((first or second or opposite) near2 (conductive or conductivity) near type)).clm. and (heavily near doped).clm. and gate.clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 15:20
30	24	(rom r (r ad near nly)) and (((first r s c nd r opposit)n ar2 (conductive r conductivity) near type)). Im. sam (h avily n ar d p d).clm. sam gate.clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 15:20